

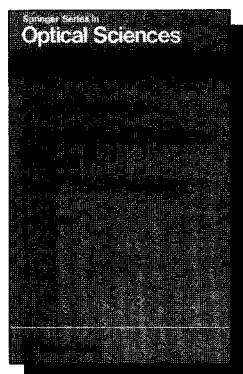
Books with numerous examples!

K.J. Ebeling, University of Ulm

Integrated Optoelectronics Waveguide Optics, Photonics, Semiconductors

1993. IX, 537 pp. 289 figs. Hardcover 98,- ISBN 3-540-56599-X

This book provides a basic understanding of the devices used in optoelectronic integrated circuits and optical signal processing such as waveguides, couplers, switches, modulators, laser diodes, and photodetectors. The descriptions start from well-known basic physical principles. The derivations are detailed and can be followed without additional references. The book contains numerous quantitative examples and, in addition, a large number of end-of-chapter problems.



R.G. Hunsperger, University of Delaware, Newark, DE

Integrated Optics: Theory and Technology

3rd ed. 1991. XIX, 347 pp. 192 figs.
17 tabs. (Springer Series in Optical Sciences, Vol. 33) Softcover DM 82,-
ISBN 3-540-53305-2

Integrated Optics is comprehensive and thorough enough for use both as a classroom text (practice problems are included) and as a specialist's reference. The gratifying success of the first two editions and the continuing rapid development of the field necessitated the writing of this third edition. All chapters have been revised and updated, and a new chapter on quantum well devices has been added. As in the previous editions, detailed descriptions of the phenomena, devices, and technology used in optical integrated circuits and their relationship to fiber optics are presented.



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